# INC6017AM1-TH50

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE

AEC-Q101 Compliance

#### **DESCRIPTION**

INC6017AM1 is a silicon NPN transistor.

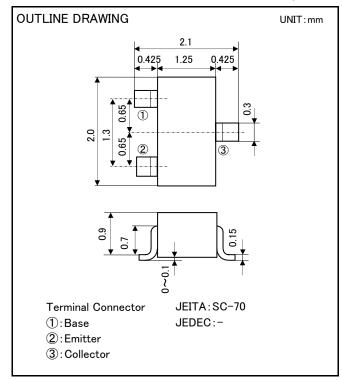
It is designed with high voltage.

#### **FEATURE**

- ·Small package for easy mounting.
- •High voltage  $V_{CEO} = 160V$
- •Low voltage VCE(sat) = 0.15V(MAX)

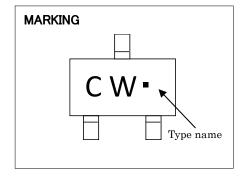
## **APPLICATION**

High voltage switching.



## MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER	RATING	UNIT
V <sub>CBO</sub>	Collector to Base voltage	180	V
$V_{EBO}$	Emitter to Base voltage	6	V
$V_{CEO}$	Collector to Emitter voltage	160	V
I <sub>CM</sub>	Peak collector current	200	mA
Ιc	Collector current	100	mA
P <sub>c</sub>	Collector dissipation(Ta=25°C)	200	mW
Tj	Junction temperature	+150	°C
$T_{stg}$	Storage temperature	-55 <b>~</b> +150	°C



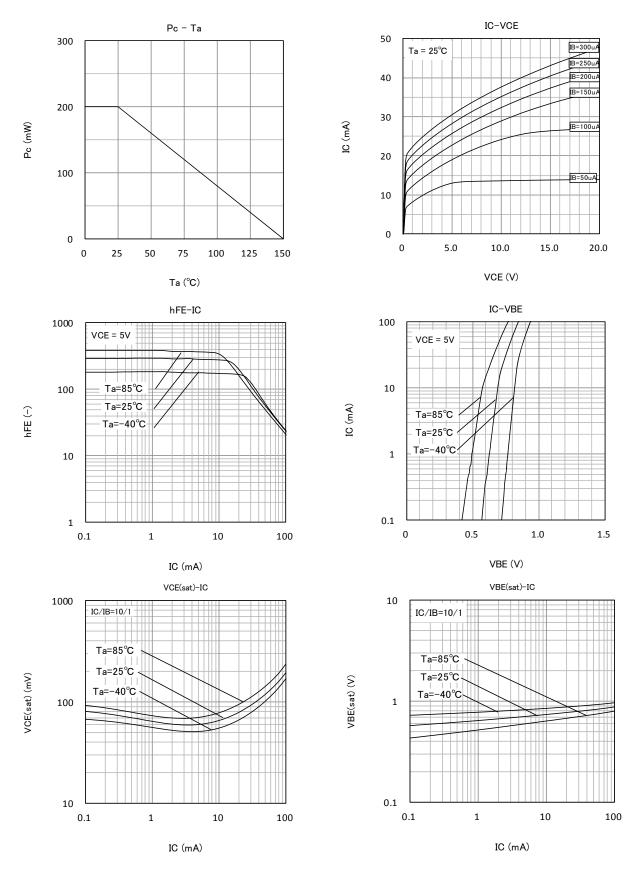
## ELECTRICAL CHARACTERISTICS (Ta=25°C)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	UNIT
V <sub>(BR)CBO</sub>	C to B breakdown voltage	I <sub>c</sub> =100uA, I <sub>E</sub> =0	180	-	-	٧
V <sub>(BR)EBO</sub>	E to B breakdown voltage	I <sub>E</sub> =10uA, I <sub>C</sub> =0	6	-	-	٧
V <sub>(BR)CEO</sub>	C to E breakdown voltage	I <sub>c</sub> =1mA, R <sub>BE</sub> =∞	160	-	-	٧
I <sub>CBO</sub>	Collector cut off current	V <sub>CB</sub> =120V, I <sub>E</sub> =0	-	_	100	nA
$I_{\text{EBO}}$	Emitter cut off current	V <sub>EB</sub> =4V, I <sub>C</sub> =0	-	-	100	nA
hFE1	DC forward current gain1	VCE=5V, I <sub>c</sub> =1mA	150	-	-	-
hFE2	DC forward current gain2	VCE=5V, I <sub>c</sub> =10mA	200	_	500	_
hFE3	DC forward current gain3	VCE=5V, I <sub>c</sub> =50mA	27	-	-	-
VCE(sat)	C to E saturation voltage	I <sub>c</sub> =10mA, I <sub>B</sub> =1mA	_	_	0.15	V
VBE(sat)	B to E saturation voltage	I <sub>c</sub> =10mA, I <sub>B</sub> =1mA	-	-	1.0	V
fT	Gain bandwidth product	VCE=10V, I <sub>E</sub> =-10mA	100	_	300	MHz
Cob	Collector output capacitance	VCB=10V, I <sub>E</sub> =0, f=1MHz	-	1.7	6	pF

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## TYPICAL CHARACTERISTICS





#### Keep safety first in your circuit designs!

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